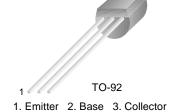


SS8050

2W Output Amplifier of Portable Radios in Class B Push-pull Operation.

- Complimentary to SS8550
- Collector Current: I_C=1.5A
- Collector Power Dissipation: P_C=2W (T_C=25°C)



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{CBO}	Collector-Base Voltage	40	V	
V _{CEO}	Collector-Emitter Voltage	25	V	
V _{EBO}	Emitter-Base Voltage	6	V	
I _C	Collector Current	1.5	Α	
P _C	Collector Power Dissipation	1	W	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	-65 ~ 150	°C	

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =100μA, I _E =0	40			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =2mA, I _B =0	25			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E=100\mu A, I_C=0$	6			V
I _{CBO}	Collector Cut-off Current	V_{CB} =35V, I_{E} =0			100	nA
I _{EBO}	Emitter Cut-off Current	V_{EB} =6V, I_{C} =0			100	nA
h _{FE1} h _{FE2} h _{FE3}	DC Current Gain	V_{CE} =1V, I_{C} =5mA V_{CE} =1V, I_{C} =100mA V_{CE} =1V, I_{C} =800mA	45 85 40	135 160 110	300	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =800mA, I _B =80mA		0.28	0.5	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =800mA, I _B =80mA		0.98	1.2	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =1V, I _C =10mA		0.66	1	V
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0 f=1MHz		9.0		pF
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =50mA	100	190		MHz

h_{FE} Classification

Classification	В	С	D
h _{FE2}	85 ~ 160	120 ~ 200	160 ~ 300

Typical Characteristics

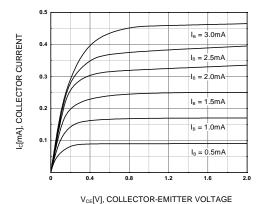


Figure 1. Static Characteristic

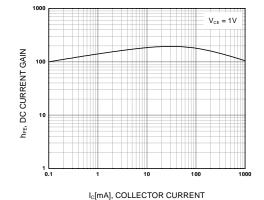


Figure 2. DC current Gain

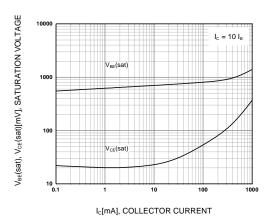


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

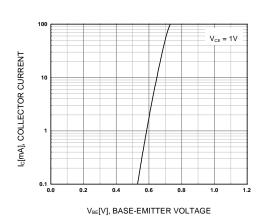


Figure 4. Base-Emitter On Voltage

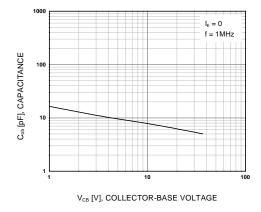


Figure 5. Collector Output Capacitance

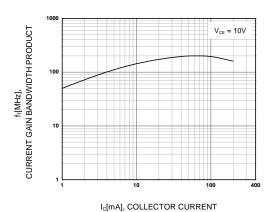


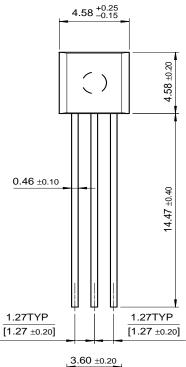
Figure 6. Current Gain Bandwidth Product

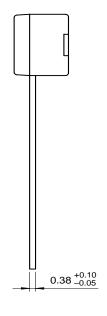
Rev. A2, November 2002

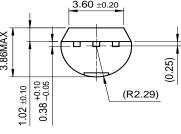
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Package Dimensions

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C TM	OCX^{TM}	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX^{TM}
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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